

Docket No.: 83028-US1
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Martin Peckerar et al.

Application No.: 10/768,747

Confirmation No.: 7954

Filed: January 23, 2004

Art Unit: 2822

For: Technique for perfecting the active regions of
wide bandgap semiconductor nitride devices

Examiner: M. F. Guerrero

RESPONSE TO FINAL ACTION UNDER 37 C.F.R. 1.116

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

INTRODUCTORY COMMENTS

In response to the Office Action dated June 6, 2006, finally rejecting claims 1-14, please see the following remarks:

Remarks/Arguments begin on page 2 of this paper.

Although it is not believed that additional fees are required along with this Response, any extension of time necessary to avoid abandonment of this application is hereby petitioned under 37 C.F.R. § 1.136(a) and any fees required are hereby authorized to be charged to Deposit Account No. 50-0281.